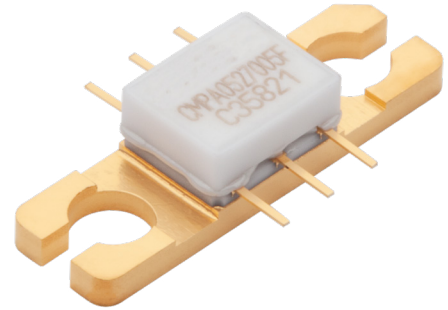


# CMPA0527005F

5 W, 0.5 - 2.7 GHz, 50 V, GaN HEMT

## Description

CMPA0527005F is a packaged gallium nitride (GaN) High Electron Mobility Transistor (HEMT) based monolithic microwave integrated circuit (MMIC). This device is matched to 50 ohms at the input and unmatched at the output. This device operates from a 50 V rail and is intended to be used as a predriver from 0.5 to 2.7 GHz. The transistor is available in a 6 leaded flange package.



Package Types: 440221  
PN: CMPA0527005F

Typical Performance Over 0.5 - 2.7 GHz ( $T_C = 25^\circ\text{C}$ ), 50 V,  $P_{IN} = 24\text{ dBm}$ , CW

Parameter	0.5 GHz	1.0 GHz	1.5 GHz	2.0 GHz	2.7 GHz	Units
Small Signal Gain	20.4	20.8	21	20.5	19.5	dB
Output Power	7.8	9.3	9.1	8.7	6.6	W
Drain Efficiency	58.5	53.8	49.2	47.1	41.5	%

Note: Measured in the CMPA0527005F-AMP1 application circuit

## Features

- Up to 2.7 GHz Operation
- 8 W Typical Output Power
- 20 dB Small Signal Gain
- Application Circuit for 0.5 - 2.7 GHz
- 50% Efficiency
- 50 V Operation



Large Signal Models Available for ADS and MWO



## Absolute Maximum Ratings (not simultaneous) at 25°C Case Temperature

Parameter	Symbol	Rating	Units	Conditions
Drain-Source Voltage	$V_{DS}$	150	V	25°C
Gate-to-Source Voltage	$V_{GS}$	-10, +2		
Storage Temperature	$T_{STG}$	-65, +150	°C	
Operating Junction Temperature	$T_J$	225		
Maximum Forward Gate Current	$I_{GMAX}$	1.2	mA	25°C
Maximum Drain Current <sup>1</sup>	$I_{DMAX}$	0.5	A	
Soldering Temperature <sup>1</sup>	$T_S$	245	°C	
Screw Torque	$\tau$	40	in-oz	
Thermal Resistance, Junction to Case <sup>2</sup>	$R_{\theta JC}$	18	°C/W	85°C
Case Operating Temperature <sup>2</sup>	$T_C$	-40, +75	°C	

Notes:

<sup>1</sup> Current limit for long term, reliable operation

<sup>2</sup> Refer to the Application Note on soldering

<sup>3</sup> Measured for the CMPA0527005F at  $P_{DISS} = 8.4$  W

<sup>4</sup> See also, Power Derating Curve on Page 5

## Electrical Characteristics ( $T_C = 25^\circ\text{C}$ )

Characteristics	Symbol	Min.	Typ.	Max.	Units	Conditions
<b>DC Characteristics<sup>1</sup></b>						
Gate Threshold	$V_{GS(th)}$	-3.8	-3.0	-2.3	$V_{DC}$	$V_{DS} = 10$ V, $I_D = 1.2$ mA
Gate Quiescent Voltage	$I_{GS(Q)}$	—	-2.7			$V_{DS} = 50$ V, $I_D = 0.11$ A
Saturated Drain Current <sup>2</sup>	$I_{DS}$	0.78	1.12		A	$V_{DS} = 6.0$ V, $V_{GS} = 2.0$ V
Drain-Source Breakdown Voltage	$V_{BR}$	100	—	—	$V_{DC}$	$V_{GS} = -8$ V, $I_D = 1.2$ mA
<b>RF Characteristics<sup>3,4,5</sup> (<math>T_C = 25^\circ\text{C}</math>, <math>F_0 = 2.7</math> GHz unless otherwise noted)</b>						
Small Signal Gain	S21	17	18.5	—	dB	$V_{DD} = 50$ V, $I_{DQ} = 0.11$ A, $P_{IN} = -10$ dBm
Power Gain	$G_P$	—	13.5	—		
Output Power	$P_{OUT}$	38.6	39.5	—	dBm	$V_{DD} = 50$ V, $I_{DQ} = 0.11$ A
Drain Efficiency	$\eta$	49	58.0	—	%	
Output Mismatch Stress	VSWR	—	—	10:1	$\Psi$	No damage at all phase angles, $V_{DD} = 50$ V, $I_{DQ} = 0.11$ A, $P_{OUT} = 5$ W CW
<b>Dynamic Characteristics<sup>6</sup></b>						
Output Capacitance at 1 MHz	$C_{DS}$	—	0.8	—	pF	$V_{DS} = 50$ V, $V_{GS} = -8$ V

Notes:

<sup>1</sup> Measured on-wafer prior to packaging

<sup>2</sup> Scaled from PCM data

<sup>3</sup> Measured in production test fixture

<sup>4</sup>  $P_{IN} = 26$  dBm

<sup>5</sup> CW

<sup>6</sup> Includes package

# CMPA0527005F Typical Performance in CMPA0527005F-AMP1 Application Circuit

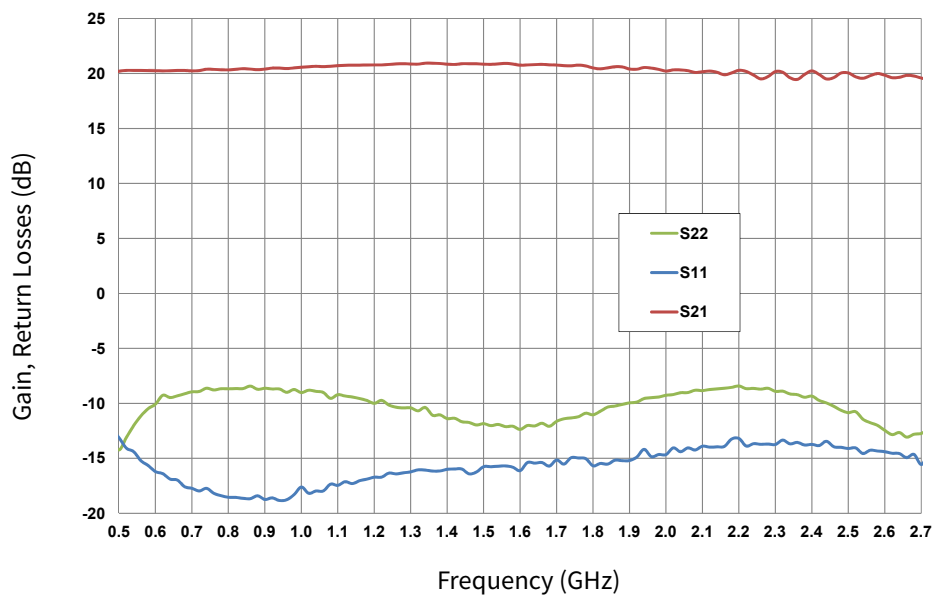


Figure 1. Small Signal Gain, Return Losses versus Frequency of the CMPA0527005F  
 $V_{DD} = 50\text{ V}$ ,  $I_{DQ} = 0.110\text{ A}$

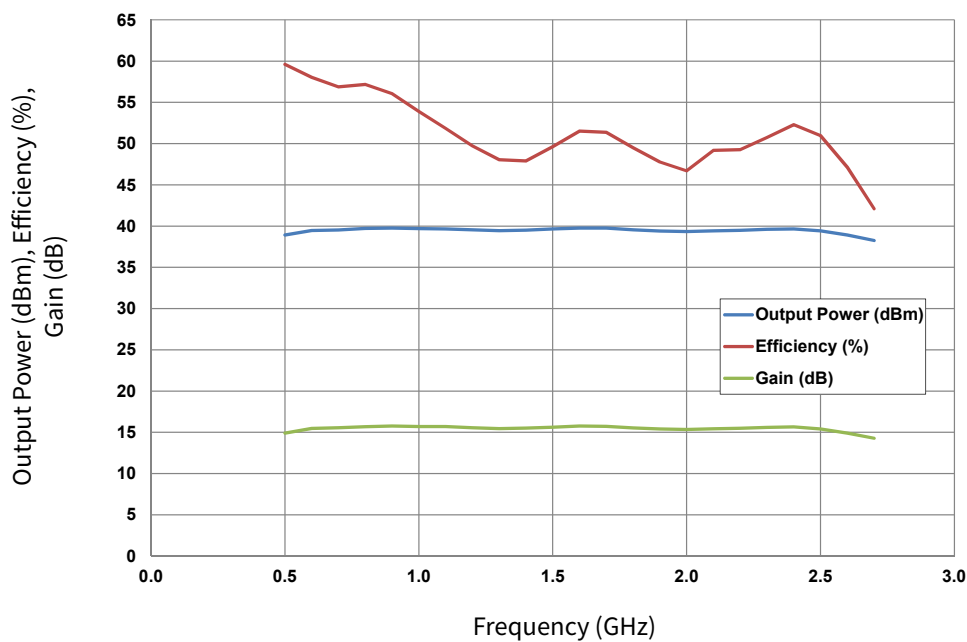


Figure 2. Output Power, Power Added Efficiency and Gain vs Frequency of the  
 CMPA0527005F as measured in demonstration amplifier circuit CMPA0527005F-AMP1  
 $V_{DD} = 50\text{ V}$ ,  $I_{DQ} = 0.110\text{ A}$ ,  $P_{IN} = 24\text{ dBm CW}$ ,  $T_C = 25^\circ\text{C}$

## CMPA0527005F Typical Performance in CMPA0527005F-AMP1 Application Circuit

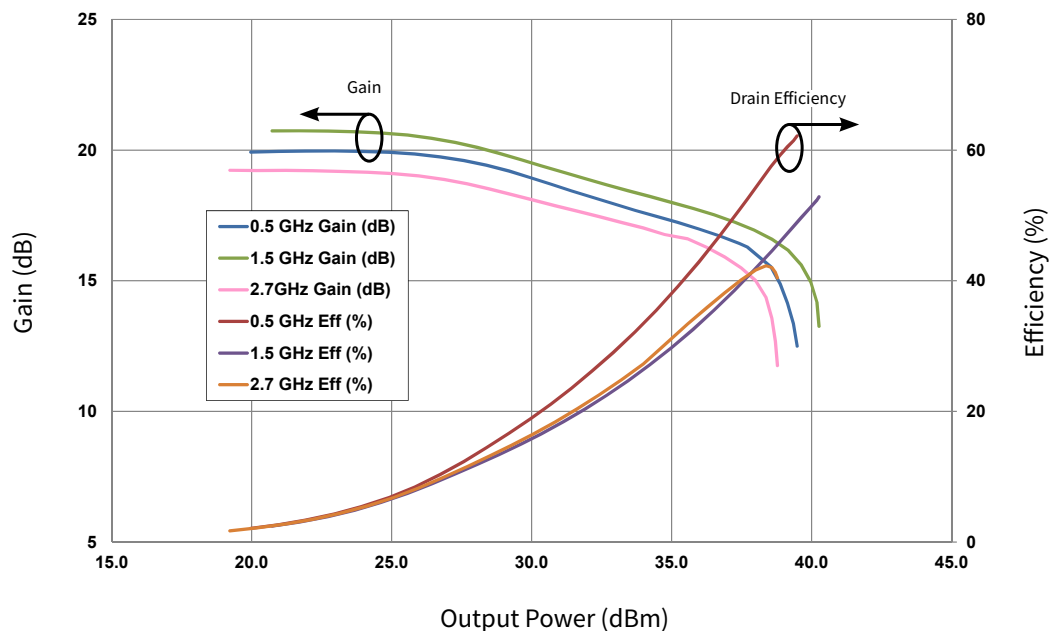


Figure 3. Gain (dB) and Efficiency (%) vs Output Power (dBm) of the CMPA0527005F as measured in demonstration amplifier circuit CMPA0527005F-AMP1  
 $V_{DD} = 50 \text{ V}$ ,  $I_{DQ} = 0.110 \text{ A}$ ,  $T_C = 25^\circ\text{C}$

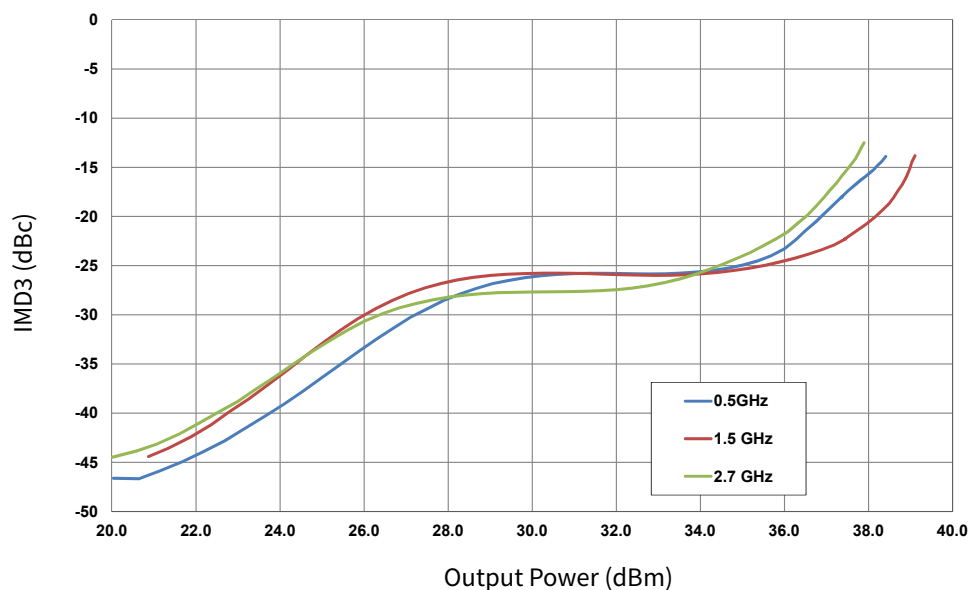


Figure 4. Third Order Intermodulation Distortion vs Output Power measured in demonstration amplifier circuit CMPA0527005F-AMP1  
 $V_{DD} = 50 \text{ V}$ ,  $I_{DQ} = 0.110 \text{ A}$ ,  $T_C = 25^\circ\text{C}$ ,  $\Delta f = 1 \text{ MHz}$

## CMPA0527005F Typical Performance

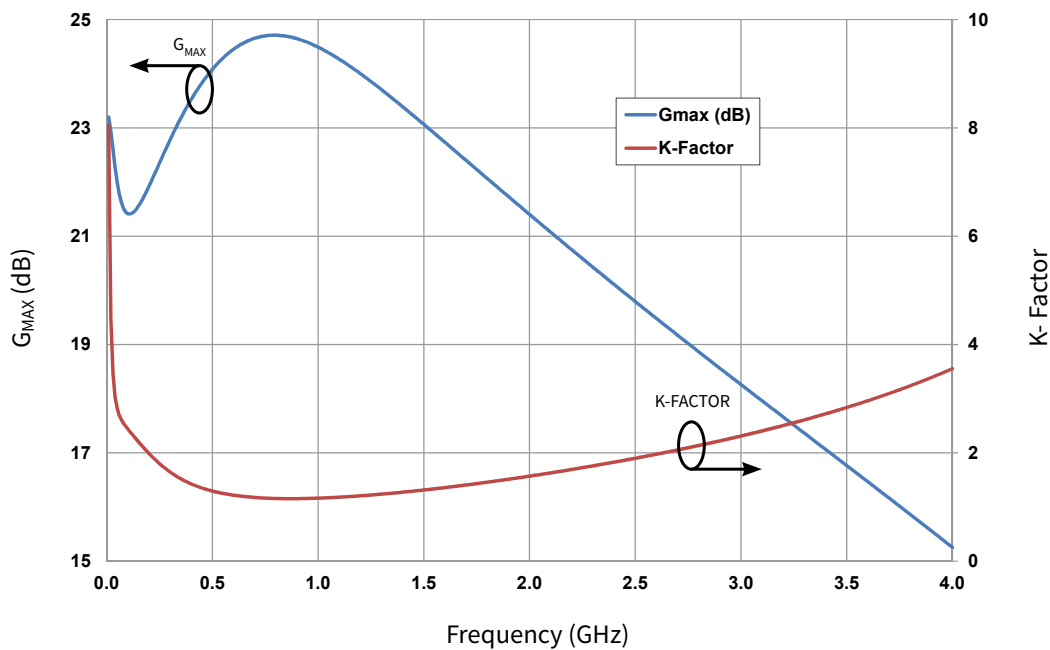


Figure 5. Simulated  $G_{MAX}$  and K-Factor vs Frequency  
 $V_{DD} = 50\text{ V}$ ,  $I_{DQ} = 0.110\text{ A}$ ,  $T_C = 25^\circ\text{C}$

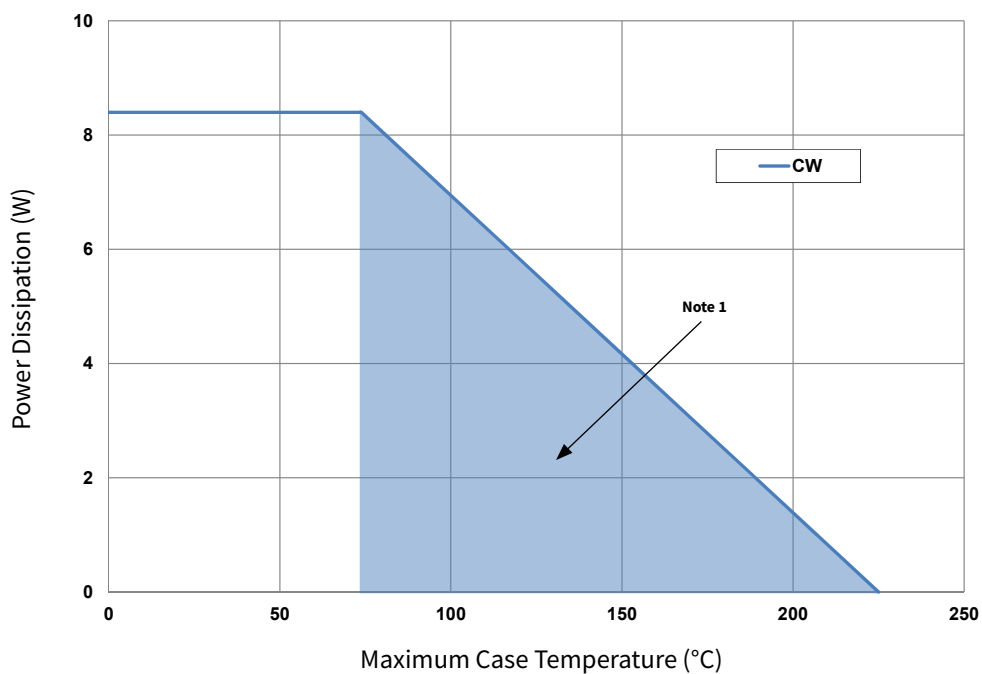
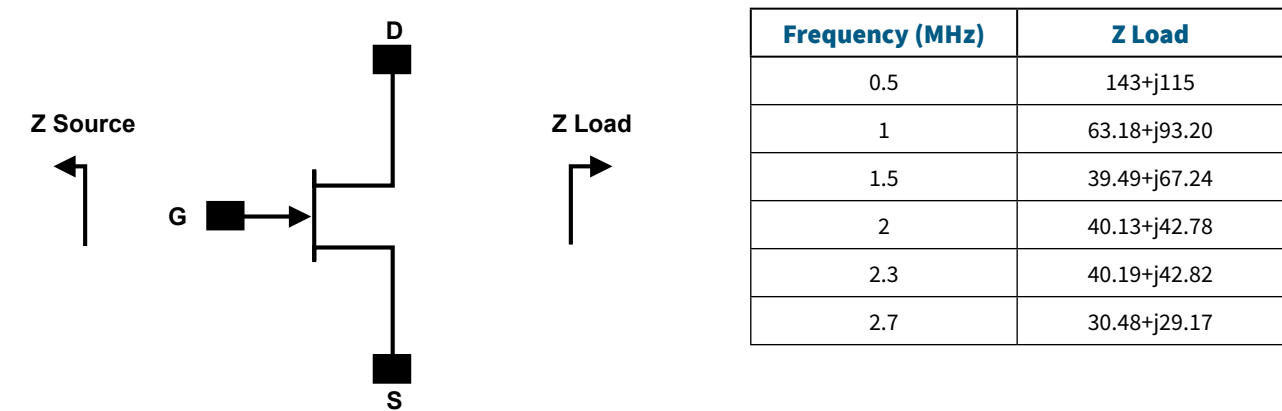


Figure 6. Transient Power Dissipation De-Rating Curve

Notes:

Shaded area exceeds Maximum Case Temperature (See Page 2).

Source and Load Impedances

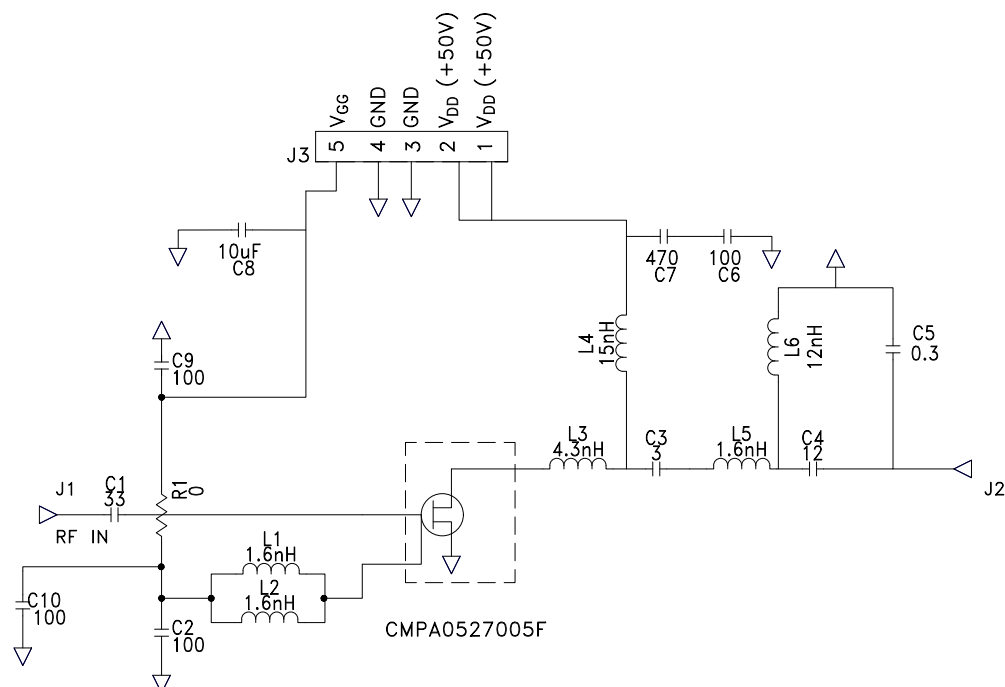


Note  
<sup>1</sup> V<sub>DD</sub> = 50 V, I<sub>DQ</sub> = 0.110 A in the 440221 package  
<sup>2</sup> Optimized for power gain, P<sub>SAT</sub> and PAE

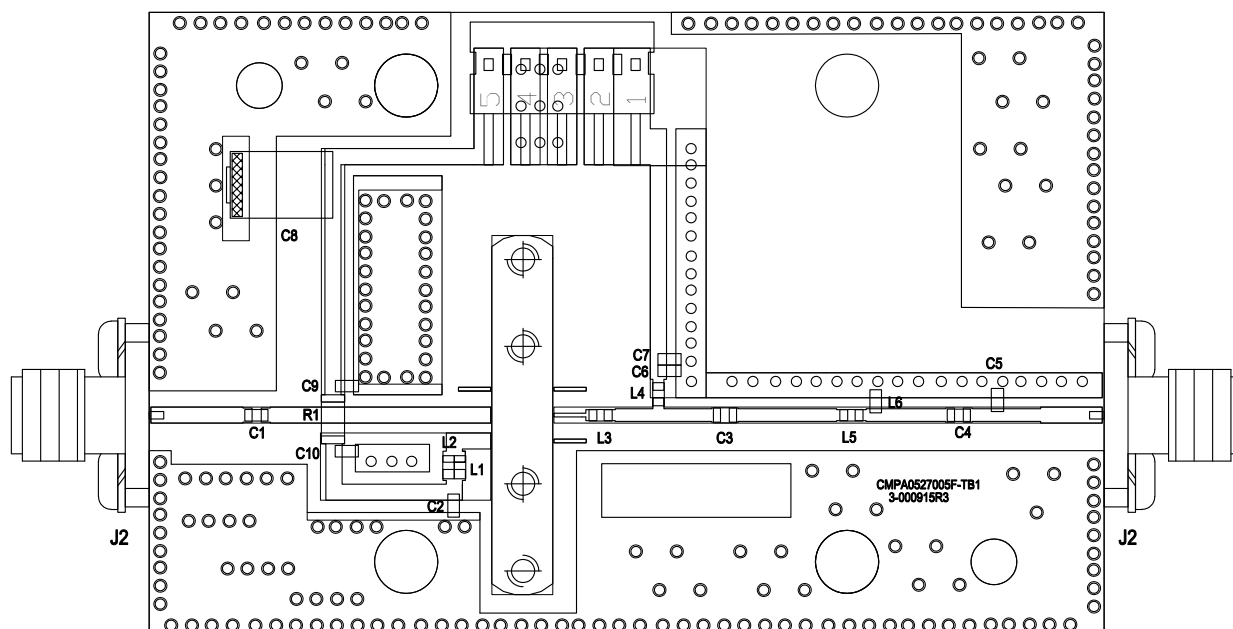
Electrostatic Discharge (ESD) Classifications

Parameter	Symbol	Class	Classification Level	Test Methodology
Human Body Model	HBM	1B	ANSI/ESDA/JEDEC JS-001 Table 3	JEDEC JESD22 A114-D
Charge Device Model	CDM	C2B	ANSI/ESDA/JEDEC JS-002 Table 3	JEDEC JESD22 C101-C

## CMPA0527005F-AMP1 Application Circuit Schematic



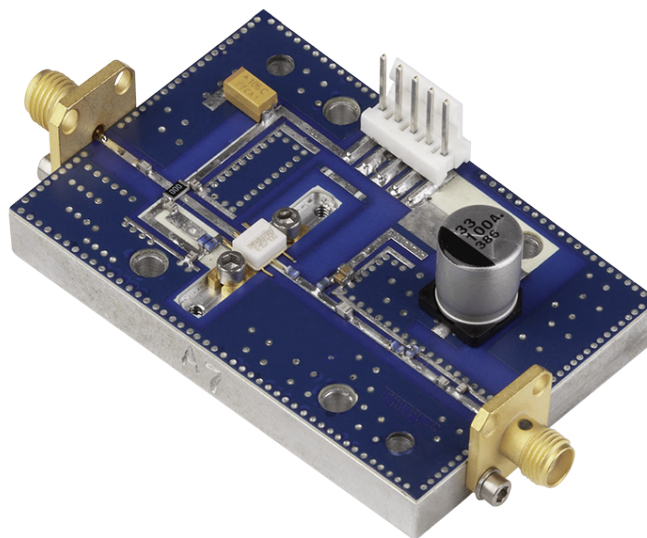
## CMPA0527005F-AMP1 Application Circuit



## CMPA0527005F-AMP1 Application Circuit Bill of Materials

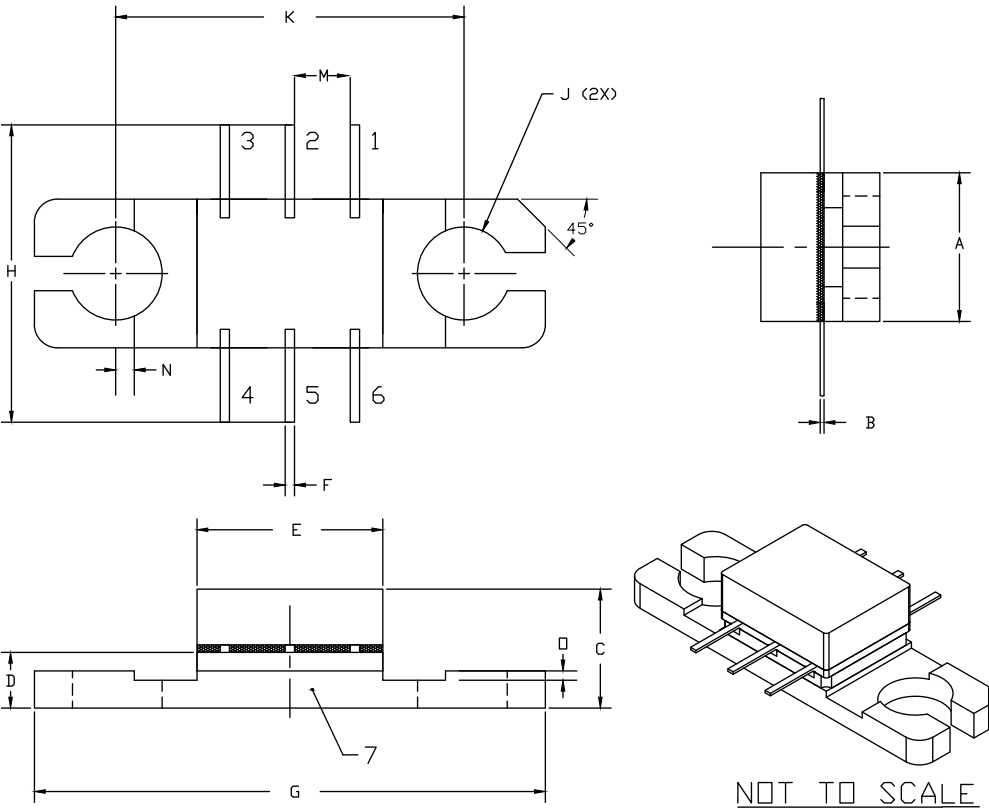
Designator	Description	Qty
C1	CAP, 33pF, 5%, 0603, ATC	1
C2, C6, C9	CAP, 100pF, 5%, 0603, ATC	3
C3	CAP, 3pF, 5%, 0805, ATC	1
C4	CAP, 12pF, 5%, 0603, ATC	1
C5	CAP, 0.3pF, 5%, 0603, ATC	1
C7	CAP, 470pF, 5%, 0603,100V. X7R	1
C8	CAP, 33000pF, 0805,100V,X7R	1
R1	RES, 1/16W, 1206, 1%, 0 Ohms	1
L1 ,L2, L5	INDUCTOR, CHIP, 1.6nH, 0603CS SMT	3
L3	INDUCTOR, CHIP, 4.3nH, 0603CS SMT	1
L4	INDUCTOR, CHIP, 15nH, 0603HP SMT	1
L6	INDUCTOR, CHIP, 12nH, 0603CS SMT	1
Q1	Transistor CMPA0527005F	1
	PCB, RO4350, CMPA0527005F Applications Board, 1.7" X 2.6" X 0.02"	1
	BASEPLATE, AL, 2.60 X 1.7 X 0.25	1
	2-56 SOC HD SCREW 1/4 SS	4
	#2 SPLIT LOCKWASHER SS	4
J1, J2	CONN, SMA, PANEL MOUNT JACK, FLANGE, 4-HOLE, BLUNT POST, 20MIL	2
J3	HEADER RT>PLZ .1CEN LK 5POS	1

## CMPA0527005F-AMP1 Demonstration Amplifier Circuit





Product Dimensions CMPA0527005F (Package Type — 440221)



- NOTES:
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  - 2. CONTROLLING DIMENSION: INCH.
  - 3. ADHESIVE FROM LID MAY EXTEND A MAXIMUM OF 0.020" BEYOND EDGE OF LID.
  - 4. LID MAY BE MISALIGNED TO THE BODY OF THE PACKAGE BY A MAXIMUM OF 0.008" IN ANY DIRECTION.
  - 5. ALL PLATED SURFACES ARE NI/AU

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.155	0.165	3.94	4.19
B	0.003	0.005	0.076	0.127
C	0.118	0.138	3.00	3.50
D	0.055	0.065	1.40	1.65
E	0.195	0.205	4.95	5.21
F	0.009	0.011	0.23	0.28
G	0.545	0.555	13.84	14.09
H	0.280	0.360	7.11	9.14
J	Ø .100		2.54	
K	0.375		9.53	
M	0.061		1.54	
N	0.018	0.022	0.46	0.56
O	0.008	0.012	0.20	0.30

NOT TO SCALE

Pin Number	Qty
1	NC
2	RF <sub>IN</sub>
3	Gate Bias
4	NC
5	RF <sub>OUT</sub> + Drain Bias
6	NC
7	Source

Part Number System

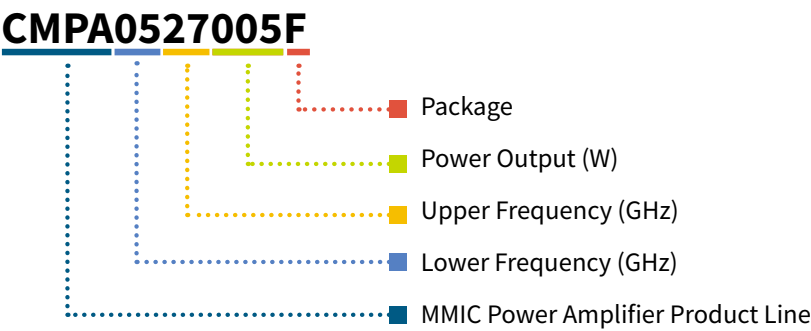


Table 1.

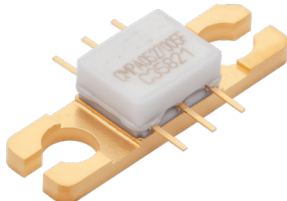
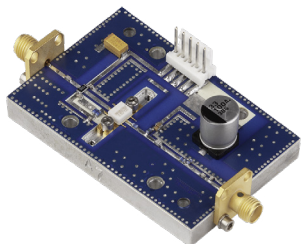
Parameter	Value	Units
Upper Frequency <sup>1</sup>	2.7	GHz
Power Output	5	W
Package	Flange	—

Note:  
<sup>1</sup> Alpha characters used in frequency code indicate a value greater than 9.9 GHz. See Table 2 for value.

Table 2.

Character Code	Code Value
A	0
B	1
C	2
D	3
E	4
F	5
G	6
H	7
J	8
K	9
Examples:	1A = 10.0 GHz 2H = 27.0 GHz

Product Ordering Information

Order Number	Description	Unit of Measure	Image
CMPA0527005F	GaN HEMT	Each	
CMPA0527005F-AMP1	Test board with GaN HEMT (flanged) installed	Each	

## Notes & Disclaimer

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